

Product Information

micomRM1200

1 KW Amplifier

Designed to work with Micom HF radio transceivers, the MicomRM 1200 power amplifier delivers the most reliable radio communications for a wide range of operational applications.

With its strict precision design, the fully solid-state amplifier features the latest and most advanced technology, providing exceptional linearity, efficiency and operating dependability for HF radio voice and data communications.





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MAXIMUM DURABILITY AND COMMUNICATION RELIABILITY

- Conservatively rated circuits deliver full power, hour after hour, for voice, CW and data (RTTY, ARQ, PACKET) service.
- The amplifier circuitry is designed for the rapid switching inherent in ARQ operation. Reliability of ARQ systems is further improved by the stronger signal from a 1 KW amplifier.
- 100% solid state, modular design - MOS-FET power transistors in interchangeable and field replaceable 300 modules - consumes less power than tube amplifiers and allows for easy servicing.
- Antenna mismatch protection prevents amplifier damage and spurious energy in case of an extreme antenna mismatch.
- With Failsoft operation, dual power supplies and parallel amplifier modules maintain operation at reduced power even in the unlikely event of total failure, allowing uninterrupted communications.
- Built-in protective circuitry ensure amplifier is not damaged during abnormal conditions.

OPTIONS

- Rack 19"
- 18 DBB1 for interface with other radios.

USER-FRIENDLINESS

- Full compatibility with all Micom radios allows maximum flexibility in systems designs. Amplifier can also operate with an existing system.
- Broadband design provides fully automatic tuning and adjustments.
- Current and Power meters allow for easy monitoring.
- Remote control panel offers convenient amplifier operating and control.
- Controller board incorporating a 16-bit micro processor centralizes all sensory status information and controls the amplifier's band selection, autotuner operation, maintenance and protective functions.
- Built-in-Test Equipment for exceptional amplifier dependability.

BITE RS232 INTERFACE PROTECTION

- Amplifier module current imbalance
- Out-of-band frequency input
- Short and Open RF output
- Input overdrive
- Over-current
- Under voltage%
- High temperature
- High VSWR

SPECIFICATIONS

Model.....FLN3175
 to be used with transceivers **micomRM125**, model: M91AMN0KV5-K & G638
micomRM125R, model: M95AMN0KV5-K & G638

Electrical

Power output1200 W PEP
 1000 W average
 (±0.5 dB) into 1.5:1 VSWR 4:1 VSWR - min 50% power
 Frequency range1.6-30 MHz
 Power input20 Watts nominal (0 dBm option)
 Harmonic emission-60 dBc
 Frequency switching Tuning process (100 msecO max between switching channels)
 Input impedance:50 Ohm
 T/R switching:10 msec maximum
 R/T switching10 msec maximum
 Rx bypass modeRx/Tx switch, active at receive

Environmental

Temperature-10°C to +60°C
 Humidity95% @ 50°C
 Input RFN type connector
 Output RFN type connector
 Control/Monitor D type 25 pins connector (including PTT, BIT, VSWR, Incident power, Tune mode, on/off)

Features

19 inch rack mountable
 Supply AC voltage90-264 VAC, 47-63% (single phase)
 Redundancy power supply (2 modules) 2 Amplifiers 600 each 125 Watt from the micom
 Automatic bypass backup
 Manual bypass selection
 Automatic step-down power levels

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